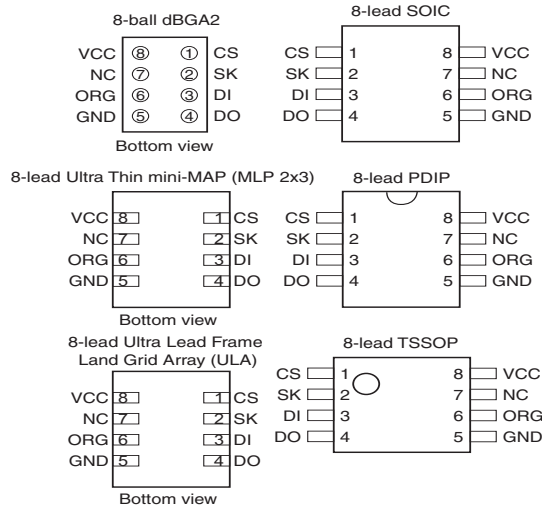


**Table 2-1. Pin Configurations**

| Pin Name | Function              |
|----------|-----------------------|
| CS       | Chip Select           |
| SK       | Serial Data Clock     |
| DI       | Serial Data Input     |
| DO       | Serial Data Output    |
| GND      | Ground                |
| VCC      | Power Supply          |
| ORG      | Internal Organization |
| NC       | No Connect            |

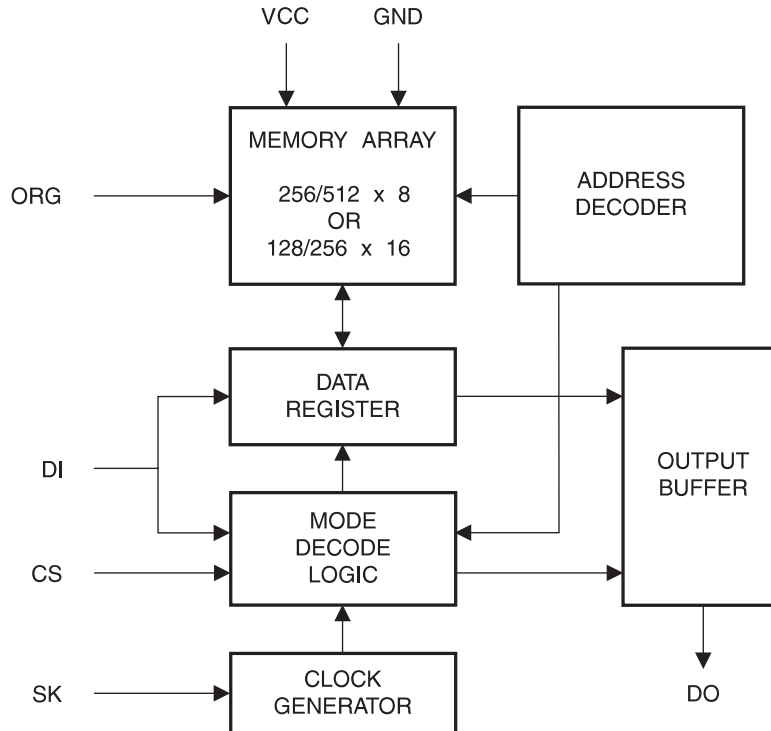


### 3. Absolute Maximum Ratings\*

|  |                 |
|--|-----------------|
| Operating Temperature .....                        | -55°C to +125°C |
| Storage Temperature.....                           | -65°C to +150°C |
| Voltage on Any Pin<br>with Respect to Ground ..... | -1.0V to +7.0V  |
| Maximum Operating Voltage .....                    | 6.25V           |
| DC Output Current.....                             | 5.0 mA          |

**\*NOTICE:** Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

Figure 3-1. Block Diagram



Note: When the ORG pin is connected to VCC, the x 16 organization is selected. When it is connected to ground, the x 8 organization is selected. If the ORG pin is left unconnected and the application does not load the input beyond the capability of the internal 1 Meg ohm pullup, then the x 16 organization is selected.

**Table 3-1.** Pin Capacitance<sup>(Note:)</sup>

 Applicable over recommended operating range from  $T_A = 25^\circ\text{C}$ ,  $f = 1.0\text{ MHz}$ ,  $V_{CC} = +5.0\text{V}$  (unless otherwise noted)

| Symbol    | Test Conditions                | Max | Units | Conditions            |
|-----------|--------------------------------|-----|-------|-----------------------|
| $C_{OUT}$ | Output Capacitance (DO)        | 5   | pF    | $V_{OUT} = 0\text{V}$ |
| $C_{IN}$  | Input Capacitance (CS, SK, DI) | 5   | pF    | $V_{IN} = 0\text{V}$  |

Note: 1. This parameter is characterized and is not 100% tested.

**Table 3-2.** DC Characteristics

 Applicable over recommended operating range from:  $T_{AI} = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ ,  $V_{CC} = +1.8\text{V}$  to  $+5.5\text{V}$ ,  $V_{CC} = +1.8\text{V}$  to  $+5.5\text{V}$  (unless otherwise noted)

| Symbol   | Parameter                                 | Test Condition                             | Min                                | Typ                         | Max                                 | Unit          |
|--|---|--|------------------------------------|-----------------------------|-------------------------------------|---------------|
| $V_{CC1}$  | Supply Voltage                            |  | 1.8                                |                             | 5.5                                 | V             |
| $V_{CC2}$  | Supply Voltage                            |  | 2.7                                |                             | 5.5                                 | V             |
| $V_{CC3}$  | Supply Voltage                            |  | 4.5                                |                             | 5.5                                 | V             |
| $I_{CC}$   | Supply Current                            | $V_{CC} = 5.0\text{V}$                     | READ at 1.0 MHz                    | 0.5                         | 2.0                                 | mA            |
|  |   |  | WRITE at 1.0 MHz                   | 0.5                         | 2.0                                 | mA            |
| $I_{SB1}$  | Standby Current                           | $V_{CC} = 1.8\text{V}$                     | CS = 0V                            | 0.4                         | 1.0                                 | $\mu\text{A}$ |
| $I_{SB2}$  | Standby Current                           | $V_{CC} = 2.7\text{V}$                     | CS = 0V                            | 6.0                         | 10.0                                | $\mu\text{A}$ |
| $I_{SB3}$  | Standby Current                           | $V_{CC} = 5.0\text{V}$                     | CS = 0V                            | 10.0                        | 15.0                                | $\mu\text{A}$ |
| $I_{IL}$   | Input Leakage                             | $V_{IN} = 0\text{V}$ to $V_{CC}$           |                                    | 0.1                         | 3.0                                 | $\mu\text{A}$ |
| $I_{OL}$   | Output Leakage                            | $V_{IN} = 0\text{V}$ to $V_{CC}$           |                                    | 0.1                         | 3.0                                 | $\mu\text{A}$ |
| $V_{IL1}$ <sup>(Note:)</sup><br>$V_{IH1}$ <sup>(Note:)</sup> | Input Low Voltage<br>Input High Voltage   | $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ |                                    | -0.6<br>2.0                 | 0.8<br>$V_{CC} + 1$                 | V             |
| $V_{IL2}$ <sup>(Note:)</sup><br>$V_{IH2}$ <sup>(Note:)</sup> | Input Low Voltage<br>Input High Voltage   | $1.8\text{V} \leq V_{CC} \leq 2.7\text{V}$ |                                    | -0.6<br>$V_{CC} \times 0.7$ | $V_{CC} \times 0.3$<br>$V_{CC} + 1$ | V             |
| $V_{OL1}$<br>$V_{OH1}$                                       | Output Low Voltage<br>Output High Voltage | $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ | $I_{OL} = 2.1\text{ mA}$           |                             | 0.4                                 | V             |
|  |   |  | $I_{OH} = -0.4\text{ mA}$          | 2.4                         |                                     | V             |
| $V_{OL2}$<br>$V_{OH2}$                                       | Output Low Voltage<br>Output High Voltage | $1.8\text{V} \leq V_{CC} \leq 2.7\text{V}$ | $I_{OL} = 0.15\text{ mA}$          |                             | 0.2                                 | V             |
|  |   |  | $I_{OH} = -100\text{ }\mu\text{A}$ | $V_{CC} - 0.2$              |                                     | V             |

 Note: 1.  $V_{IL}$  min and  $V_{IH}$  max are reference only and are not tested.

**Table 3-3. AC Characteristics**

Applicable over recommended operating range from  $T_{AI} = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{CC} = \text{As Specified}$ ,  
 $CL = 1$  TTL Gate and  $100\text{ pF}$  (unless otherwise noted)

| Symbol                       | Parameter                  | Test Condition   | Min         | Typ | Max            | Units        |
|------------------------------|----------------------------|--|-------------|-----|----------------|--------------|
| $f_{SK}$                     | SK Clock Frequency         | $4.5V \leq V_{CC} \leq 5.5V$<br>$2.7V \leq V_{CC} \leq 5.5V$<br>$1.8V \leq V_{CC} \leq 5.5V$ | 0<br>0<br>0 |     | 2<br>1<br>0.25 | MHz          |
| $t_{SKH}$                    | SK High Time               | $2.7V \leq V_{CC} \leq 5.5V$<br>$1.8V \leq V_{CC} \leq 5.5V$                                 | 250<br>1000 |     |                | ns           |
| $t_{SKL}$                    | SK Low Time                | $2.7V \leq V_{CC} \leq 5.5V$<br>$1.8V \leq V_{CC} \leq 5.5V$                                 | 250<br>1000 |     |                | ns           |
| $t_{CS}$                     | Minimum CS Low Time        | $2.7V \leq V_{CC} \leq 5.5V$<br>$1.8V \leq V_{CC} \leq 5.5V$                                 | 250<br>1000 |     |                | ns           |
| $t_{CSS}$                    | CS Setup Time              | Relative to SK<br>$2.7V \leq V_{CC} \leq 5.5V$<br>$1.8V \leq V_{CC} \leq 5.5V$               | 50<br>200   |     |                | ns           |
| $t_{DIS}$                    | DI Setup Time              | Relative to SK<br>$2.7V \leq V_{CC} \leq 5.5V$<br>$1.8V \leq V_{CC} \leq 5.5V$               | 100<br>400  |     |                | ns           |
| $t_{CSH}$                    | CS Hold Time               | Relative to SK   | 0           |     |                | ns           |
| $t_{DIH}$                    | DI Hold Time               | Relative to SK<br>$2.7V \leq V_{CC} \leq 5.5V$<br>$1.8V \leq V_{CC} \leq 5.5V$               | 100<br>400  |     |                | ns           |
| $t_{PD1}$                    | Output Delay to "1"        | AC Test<br>$2.7V \leq V_{CC} \leq 5.5V$<br>$1.8V \leq V_{CC} \leq 5.5V$                      |             |     | 250<br>1000    | ns           |
| $t_{PD0}$                    | Output Delay to "0"        | AC Test<br>$2.7V \leq V_{CC} \leq 5.5V$<br>$1.8V \leq V_{CC} \leq 5.5V$                      |             |     | 250<br>1000    | ns           |
| $t_{SV}$                     | CS to Status Valid         | AC Test<br>$2.7V \leq V_{CC} \leq 5.5V$<br>$1.8V \leq V_{CC} \leq 5.5V$                      |             |     | 250<br>1000    | ns           |
| $t_{DF}$                     | CS to DO in High Impedance | AC Test<br>CS = $V_{IL}$<br>$2.7V \leq V_{CC} \leq 5.5V$<br>$1.8V \leq V_{CC} \leq 5.5V$     |             |     | 150<br>400     | ns           |
| $t_{WP}$                     | Write Cycle Time           | $1.8V \leq V_{CC} \leq 5.5V$   | 0.1         | 3   | 10             | ms           |
| Endurance <sup>(Note:)</sup> | 5.0V, 25°C                 |  | 1M          |     |                | Write Cycles |

Note: 1. This parameter is characterized and is not 100% tested.

**Table 3-4.** Instruction Set for the AT93C56A and AT93C66A

| Instruction | SB | Op Code | Address     |             | Data        |                | Comments  |
|-------------|----|---------|-------------|-------------|-------------|----------------|---|
|             |    |         | x 8         | x 16        | x 8         | x 16           |   |
| READ        | 1  | 10      | $A_8 - A_0$ | $A_7 - A_0$ |             |                | Reads data stored in memory, at specified address.  |
| EWEN        | 1  | 00      | 11XXXXXXXX  | 11XXXXXXX   |             |                | Write enable must precede all programming modes.  |
| ERASE       | 1  | 11      | $A_8 - A_0$ | $A_7 - A_0$ |             |                | Erases memory location $A_n - A_0$ .  |
| WRITE       | 1  | 01      | $A_8 - A_0$ | $A_7 - A_0$ | $D_7 - D_0$ | $D_{15} - D_0$ | Writes memory location $A_n - A_0$ .  |
| ERAL        | 1  | 00      | 10XXXXXXXX  | 10XXXXXXX   |             |                | Erases all memory locations. Valid only at $V_{CC} = 4.5V$ to $5.5V$ .                            |
| WRAL        | 1  | 00      | 01XXXXXXXX  | 01XXXXXXX   | $D_7 - D_0$ | $D_{15} - D_0$ | Writes all memory locations. Valid only at $V_{CC} = 5.0V \pm 10\%$ and Disable Register cleared. |
| EWDS        | 1  | 00      | 00XXXXXXXX  | 00XXXXXXX   |             |                | Disables all programming instructions.  |

Note: The X's in the address field represent don't care values and must be clocked.

## 4. Functional Description

The AT93C56A/66A is accessed via a simple and versatile three-wire serial communication interface. Device operation is controlled by seven instructions issued by the host processor. **A valid instruction starts with a rising edge of CS** and consists of a Start Bit (logic “1”) followed by the appropriate Op Code and the desired memory address location.

**READ (READ):** The Read (READ) instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the serial output pin DO. Output data changes are synchronized with the rising edges of serial clock SK. It should be noted that a dummy bit (logic “0”) precedes the 8- or 16-bit data output string. The AT93C56A/66A supports sequential read operations. The device will automatically increment the internal address pointer and clock out the next memory location as long as Chip Select (CS) is held high. In this case, the dummy bit (logic “0”) will not be clocked out between memory locations, thus allowing for a continuous stream of data to be read.

**ERASE/WRITE (EWEN):** To assure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable (EWEN) instruction must be executed first before any programming instructions can be carried out. Please note that once in the EWEN state, programming remains enabled until an EWDS instruction is executed or  $V_{CC}$  power is removed from the part.

**ERASE (ERASE):** The Erase instruction programs all bits in the specified memory location to the logical “1” state. The self-timed erase cycle starts once the ERASE instruction and address are decoded. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). A logic “1” at pin DO indicates that the selected memory location has been erased, and the part is ready for another instruction.

**WRITE (WRITE):** The Write (WRITE) instruction contains the 8 or 16 bits of data to be written into the specified memory location. The self-timed programming cycle  $t_{WP}$  starts after the last bit of data is received at serial data input pin DI. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). A logic “0” at DO indicates that programming is still in progress. A logic “1” indicates that the memory location at the specified address has been written with the data pattern contained in the instruction and the part is ready for further instructions. **A READY/BUSY status cannot be obtained if the CS is brought high after the end of the self-timed programming cycle  $t_{WP}$ .**

**ERASE ALL (ERAL):** The Erase All (ERAL) instruction programs every bit in the memory array to the logic “1” state and is primarily used for testing purposes. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). The ERAL instruction is valid only at  $V_{CC} = 5.0V \pm 10\%$ .

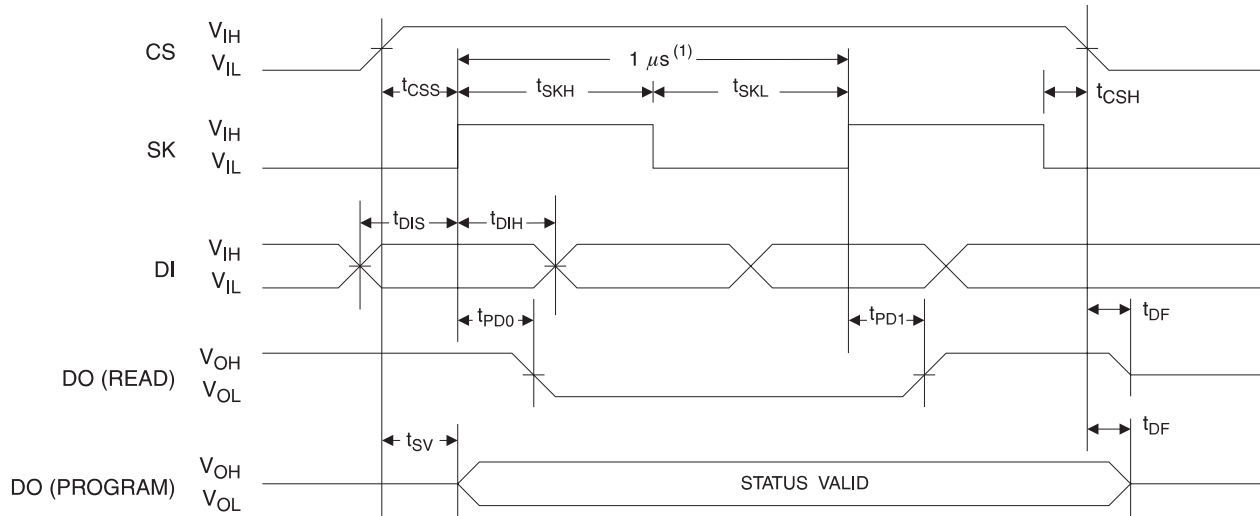
**WRITE ALL (WRAL):** The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). The WRAL instruction is valid only at  $V_{CC} = 5.0V \pm 10\%$ .

**ERASE/WRITE DISABLE (EWDS):** To protect against accidental data disturb, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the READ instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.



## 5. Timing Diagrams

Figure 5-1. Synchronous Data Timing



Note: 1. This is the minimum SK period.

Table 5-1. Organization Key for Timing Diagrams

| I/O   | AT93C56A (2K) |             | AT93C66A (4K) |          |
|-------|---------------|-------------|---------------|----------|
|       | x 8           | x 16        | x 8           | x 16     |
| $A_N$ | $A_8^{(1)}$   | $A_7^{(2)}$ | $A_8$         | $A_7$    |
| $D_N$ | $D_7$         | $D_{15}$    | $D_7$         | $D_{15}$ |

Notes: 1.  $A_8$  is a DON'T CARE value, but the extra clock is required.  
 2.  $A_7$  is a DON'T CARE value, but the extra clock is required.

Figure 5-2. READ Timing

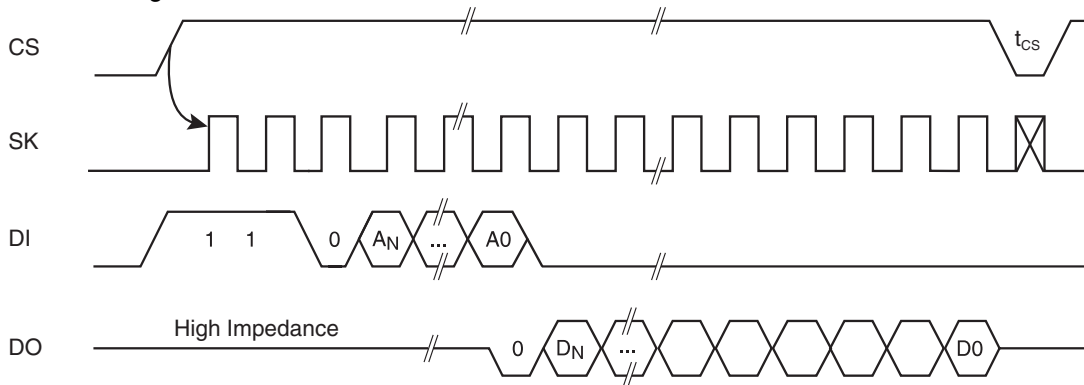


Figure 5-3. EWEN Timing

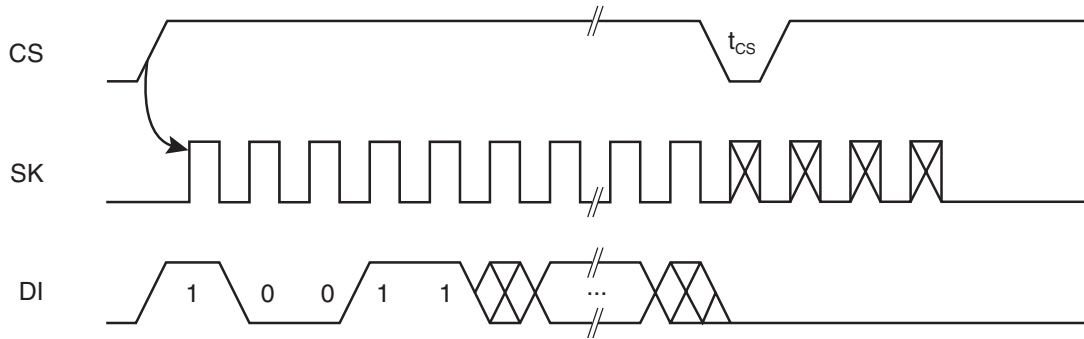


Figure 5-4. EWDS Timing

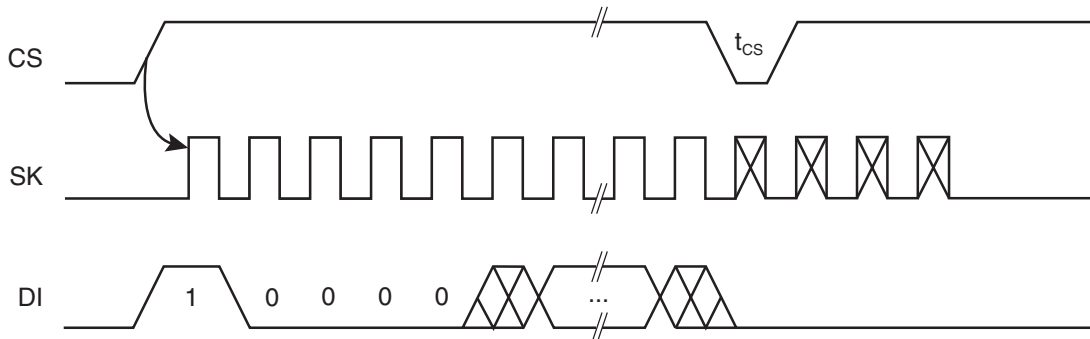
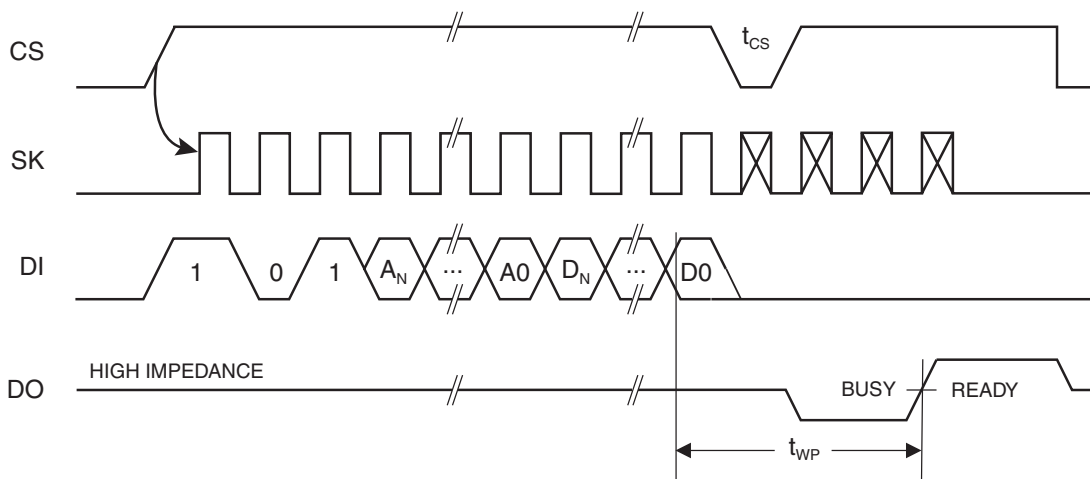
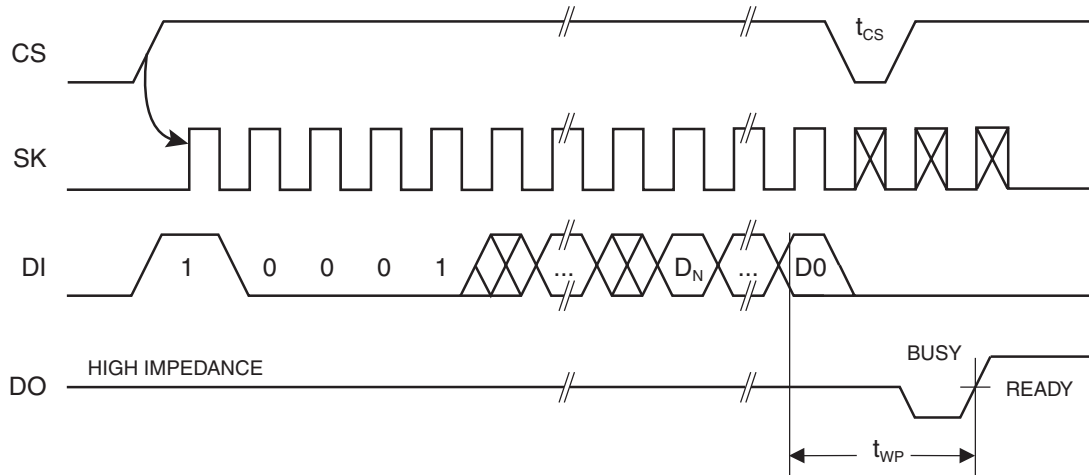


Figure 5-5. WRITE Timing





**Figure 5-6.** WRAL Timing<sup>(1)</sup>



Note: 1. Valid only at  $V_{CC} = 4.5V$  to  $5.5V$ .

**Figure 5-7.** ERASE Timing

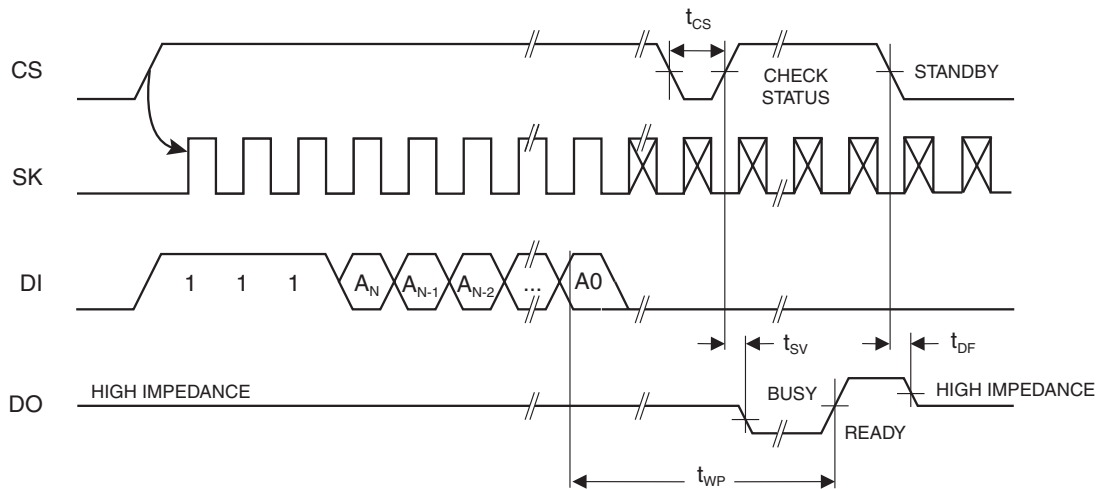
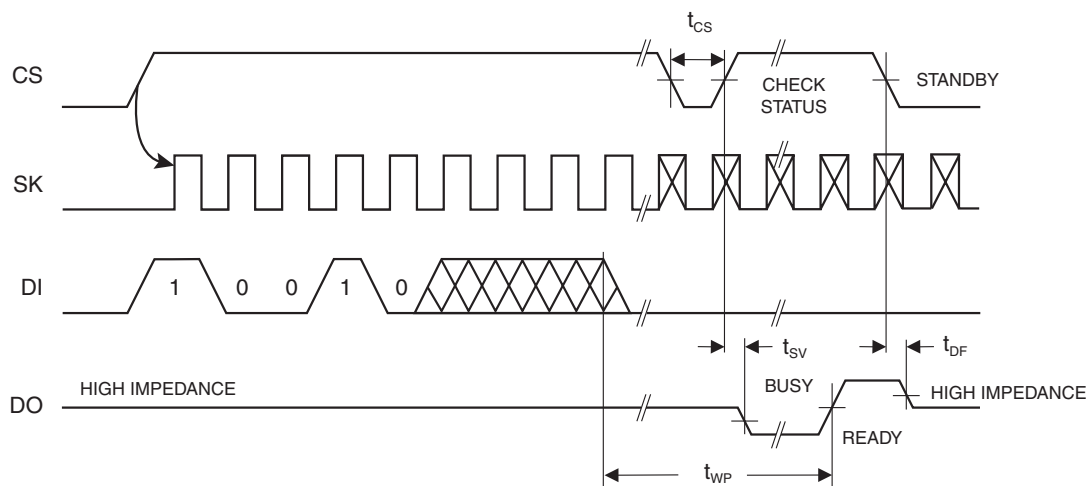


Figure 5-8. ERAL Timing<sup>(1)</sup>



Note: 1. Valid only at  $V_{CC} = 4.5V$  to  $5.5V$ .



## 6. AT93C56A Ordering Information<sup>(1)</sup>

| Ordering Code   | Package   | Operation Range  |
|---|-----------|--|
| AT93C56A-10PU-2.7 <sup>(2)</sup>                                    | 8P3       | Lead-free/Halogen-free/<br>Industrial Temperature<br>(-40°C to 85°C) |
| AT93C56A-10PU-1.8 <sup>(2)</sup>                                    | 8P3       |  |
| AT93C56A-10SU-2.7 <sup>(2)</sup>                                    | 8S1       |  |
| AT93C56A-10SU-1.8 <sup>(2)</sup>                                    | 8S1       |  |
| AT93C56AW-10SU-2.7 <sup>(2)</sup>                                   | 8S2       |  |
| AT93C56AW-10SU-1.8 <sup>(2)</sup>                                   | 8S2       |  |
| AT93C56A-10TU-2.7 <sup>(2)</sup>                                    | 8A2       |  |
| AT93C56A-10TU-1.8 <sup>(2)</sup>                                    | 8A2       |  |
| AT93C56AU3-10UU-1.8 <sup>(2)</sup>                                  | 8U3-1     |  |
| AT93C56AD3-10DH-1.8 <sup>(3)</sup>                                  | 8D3       |  |
| AT93C56AY1-10YU-1.8 <sup>(2)</sup> (Not recommended for new design) | 8Y1       |  |
| AT93C56AY6-10YH-1.8 <sup>(3)</sup>                                  | 8Y6       |  |
| AT93C56A-W1.8-11 <sup>(4)</sup>                                     | Die Sales | Industrial Temperature<br>(-40°C to 85°C)                            |

- Notes:
1. For 2.7V devices used in the 4.5V to 5.5V range, please refer to performance values in the AC and DC characteristics table.
  2. "U" designates Green package + RoHS compliant.
  3. "H" designates Green package + RoHS compliant, with NiPdAu Lead Finish.
  4. Available in waffle pack and wafer form; order as SL788 for inkless wafer form. Bumped die available upon request. Please contact Serial Marketing.

| Package Type |  |
|--------------|--|
| <b>8P3</b>   | 8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)  |
| <b>8S1</b>   | 8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)  |
| <b>8S2</b>   | 8-lead, 0.200" Wide, Plastic Gull Wing Small Outline (EIAJ SOIC)   |
| <b>8A2</b>   | 8-lead, 0.170" Wide, Thin Shrink Small Outline Package (TSSOP)   |
| <b>8U3-1</b> | 8-ball, die Ball Grid Array Package (dBGAA2)   |
| <b>8Y1</b>   | 8-lead, 4.90 mm x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP)                    |
| <b>8Y6</b>   | 8-lead, 2.00 mm x 3.00 mm Body, 0.50 mm Pitch, Ultra Thin Mini-MAP, Dual No Lead package (DFN), (MLP 2x3 mm) |
| <b>8D3</b>   | 8-lead, 1.80 mm x 2.20 mm Body, Ultra Lead Frame Land Grid Array (ULA)                                       |
| Options      |  |
| <b>-2.7</b>  | Low-voltage (2.7V to 5.5V)   |
| <b>-1.8</b>  | Low-voltage (1.8V to 5.5V)   |

## 7. AT93C66A Ordering Information<sup>(1)</sup>

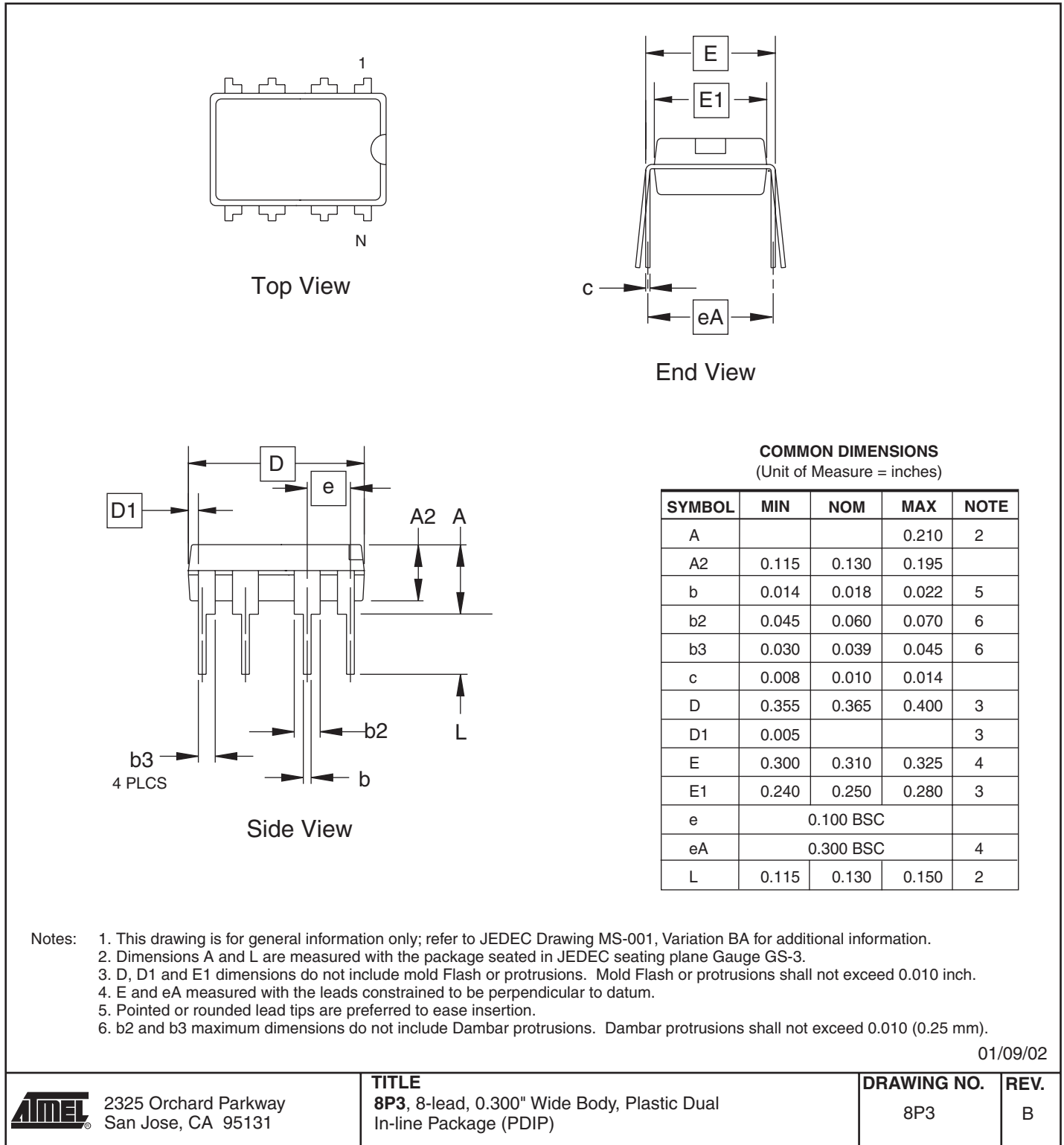
| Ordering Code   | Package  | Operation Range  |
|---|----------|--|
| AT93C66A-10PU-2.7 <sup>(2)</sup>                                    | 8P3      | Lead-free/Halogen-free/<br>Industrial Temperature<br>(-40°C to 85°C) |
| AT93C66A-10PU-1.8 <sup>(2)</sup>                                    | 8P3      |  |
| AT93C66A-10SU-2.7 <sup>(2)</sup>                                    | 8S1      |  |
| AT93C66A-10SU-1.8 <sup>(2)</sup>                                    | 8S1      |  |
| AT93C66AW-10SU-2.7 <sup>(2)</sup>                                   | 8S2      |  |
| AT93C66AW-10SU-1.8 <sup>(2)</sup>                                   | 8S2      |  |
| AT93C66A-10TU-2.7 <sup>(2)</sup>                                    | 8A2      |  |
| AT93C66A-10TU-1.8 <sup>(2)</sup>                                    | 8A2      |  |
| AT93C66AU3-10UU-1.8 <sup>(2)</sup>                                  | 8U3-1    |  |
| AT93C66AD3-10DH-1.8 <sup>(3)</sup>                                  | 8D3      |  |
| AT93C66AY1-10YU-1.8 <sup>(2)</sup> (Not recommended for new design) | 8Y1      |  |
| AT93C66AY6-10YH-1.8 <sup>(3)</sup>                                  | 8Y6      |  |
| AT93C66A-W1.8-11 <sup>(4)</sup>                                     | Die Sale | Industrial Temperature<br>(-40°C to 85°C)                            |

- Notes:
- For 2.7V devices used in the 4.5V to 5.5V range, please refer to performance values in the AC and DC characteristics table.
  - “U” designates Green package + RoHS compliant.
  - “H” designates Green package + RoHS compliant, with NiPdAu Lead Finish.
  - Available in waffle pack and wafer form; order as SL788 for inkless wafer form. Bumped die available upon request. Please contact Serial EEPROM Marketing.

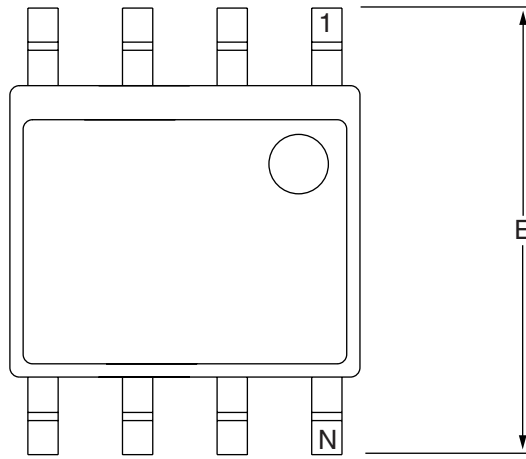
| Package Type |  |
|--------------|--|
| <b>8P3</b>   | 8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)  |
| <b>8S1</b>   | 8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)  |
| <b>8S2</b>   | 8-lead, 0.200" Wide, Plastic Gull Wing Small Outline (EIAJ SOIC)   |
| <b>8A2</b>   | 8-lead, 0.170" Wide, Thin Shrink Small Outline Package (TSSOP)   |
| <b>8U3-1</b> | 8-ball, die Ball Grid Array Package (dBGAA2)   |
| <b>8Y1</b>   | 8-lead, 4.90 mm x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP)                    |
| <b>8Y6</b>   | 8-lead, 2.00 mm x 3.00 mm Body, 0.50 mm Pitch, Ultra Thin Mini-MAP, Dual No Lead package (DFN), (MLP 2x3 mm) |
| <b>8D3</b>   | 8-lead, 1.80 mm x 2.20 mm Body, Ultra Lead Frame Land Grid Array (ULA)                                       |
| Options      |  |
| <b>-2.7</b>  | Low-voltage (2.7V to 5.5V)   |
| <b>-1.8</b>  | Low-voltage (1.8V to 5.5V)   |

## 8. Packaging Information

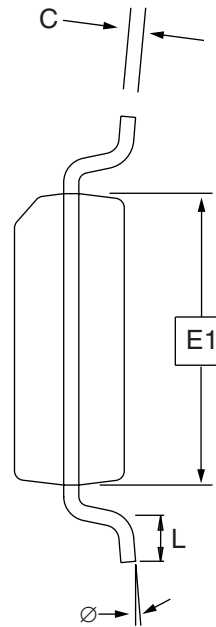
### 8.1 8P3 – PDIP



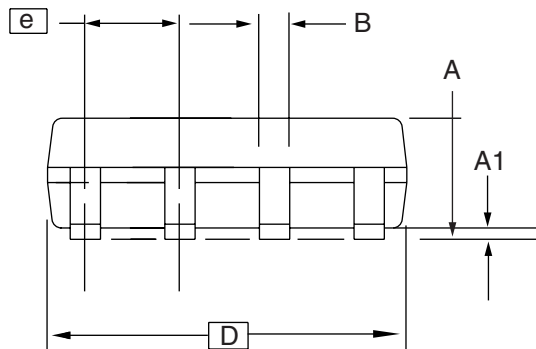
8.2 8S1 – JEDEC SOIC



Top View



End View



Side View

COMMON DIMENSIONS  
(Unit of Measure = mm)

| SYMBOL | MIN      | NOM | MAX  | NOTE |
|--------|----------|-----|------|------|
| A      | 1.35     | –   | 1.75 |      |
| A1     | 0.10     | –   | 0.25 |      |
| b      | 0.31     | –   | 0.51 |      |
| C      | 0.17     | –   | 0.25 |      |
| D      | 4.80     | –   | 5.00 |      |
| E1     | 3.81     | –   | 3.99 |      |
| E      | 5.79     | –   | 6.20 |      |
| e      | 1.27 BSC |     |      |      |
| L      | 0.40     | –   | 1.27 |      |
| ∅      | 0°       | –   | 8°   |      |

Note: These drawings are for general information only. Refer to JEDEC Drawing MS-012, Variation AA for proper dimensions, tolerances, datums, etc.

10/7/03



1150 E. Cheyenne Mtn. Blvd.  
Colorado Springs, CO 80906

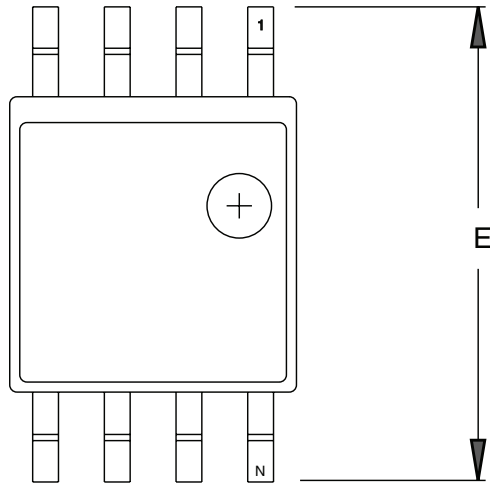
**TITLE**  
8S1, 8-lead (0.150" Wide Body), Plastic Gull Wing  
Small Outline (JEDEC SOIC)

**DRAWING NO.**  
8S1

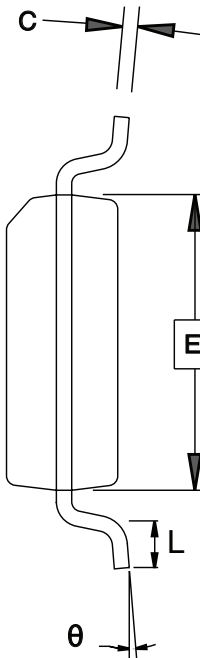
**REV.**  
B



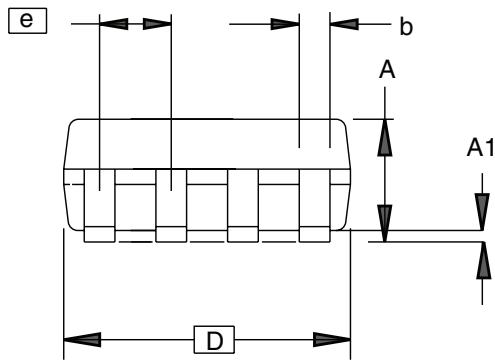
### 8.3 8S2 – EIAJ SOIC



TOP VIEW



END VIEW



SIDE VIEW

COMMON DIMENSIONS  
(Unit of Measure = mm)

| SYMBOL   | MIN      | NOM | MAX  | NOTE |
|----------|----------|-----|------|------|
| A        | 1.70     |     | 2.16 |      |
| A1       | 0.05     |     | 0.25 |      |
| b        | 0.35     |     | 0.48 | 5    |
| C        | 0.15     |     | 0.35 | 5    |
| D        | 5.13     |     | 5.35 |      |
| E1       | 5.18     |     | 5.40 | 2, 3 |
| E        | 7.70     |     | 8.26 |      |
| L        | 0.51     |     | 0.85 |      |
| $\theta$ | 0°       |     | 8°   |      |
| e        | 1.27 BSC |     |      | 4    |

- Notes: 1. This drawing is for general information only; refer to EIAJ Drawing EDR-7320 for additional information.  
 2. Mismatch of the upper and lower dies and resin burrs aren't included.  
 3. It is recommended that upper and lower cavities be equal. If they are different, the larger dimension shall be regarded.  
 4. Determines the true geometric position.  
 5. Values b,C apply to plated terminal. The standard thickness of the plating layer shall measure between 0.007 to .021 mm.

04/07/06



2325 Orchard Parkway  
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**TITLE**

**8S2**, 8-lead, 0.209" Body, Plastic Small  
Outline Package (EIAJ)

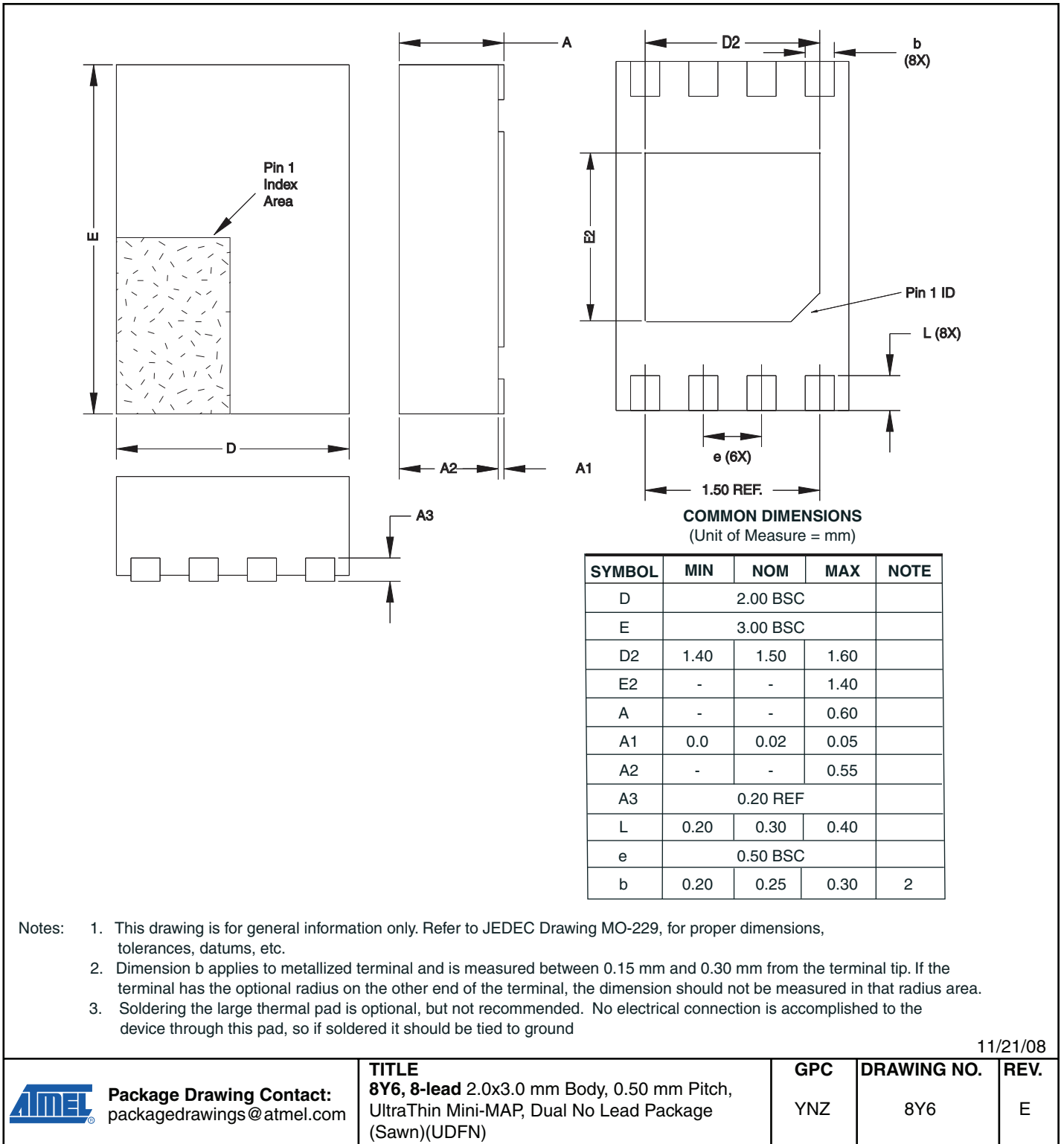
**DRAWING NO.**

8S2

**REV.**

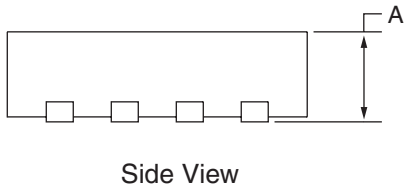
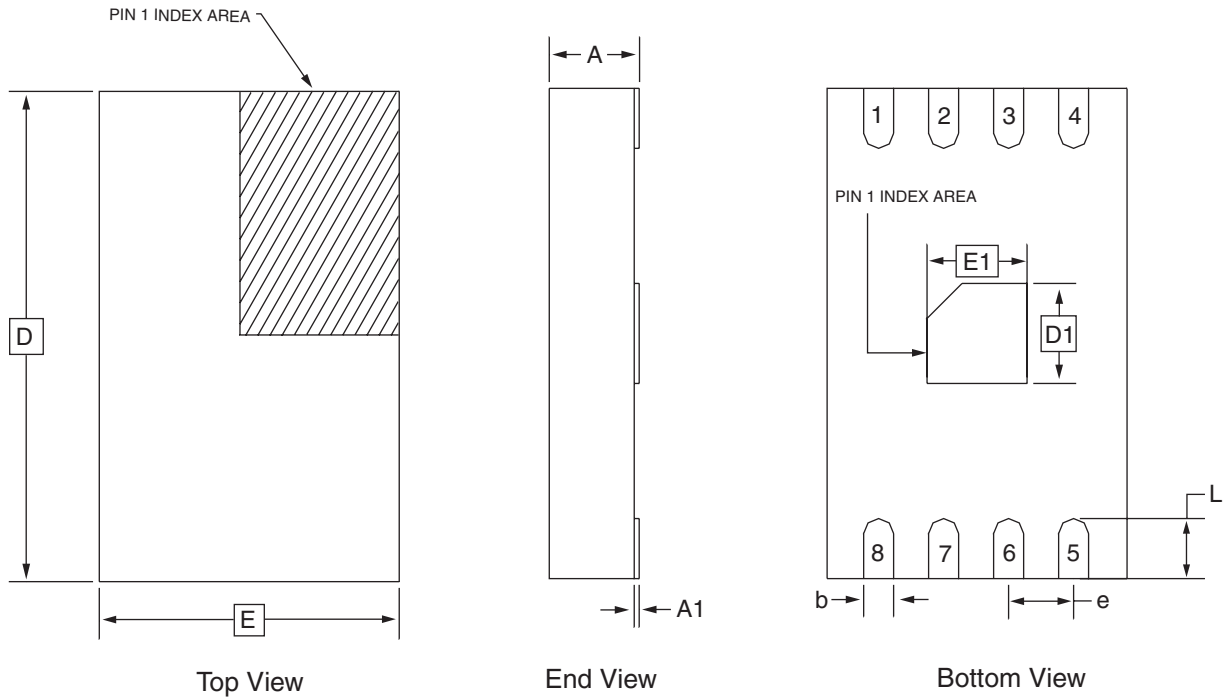
D

8.4 8Y6 – MiniMap (MLP 2x3)





### 8.5 8Y1 – Map



**COMMON DIMENSIONS**  
(Unit of Measure = mm)

| SYMBOL | MIN      | NOM  | MAX  | NOTE |
|--------|----------|------|------|------|
| A      | –        | –    | 0.90 |      |
| A1     | 0.00     | –    | 0.05 |      |
| D      | 4.70     | 4.90 | 5.10 |      |
| E      | 2.80     | 3.00 | 3.20 |      |
| D1     | 0.85     | 1.00 | 1.15 |      |
| E1     | 0.85     | 1.00 | 1.15 |      |
| b      | 0.25     | 0.30 | 0.35 |      |
| e      | 0.65 TYP |      |      |      |
| L      | 0.50     | 0.60 | 0.70 |      |

2/28/03



2325 Orchard Parkway  
San Jose, CA 95131

**TITLE**

**8Y1**, 8-lead (4.90 x 3.00 mm Body) MSOP Array Package  
(MAP) Y1

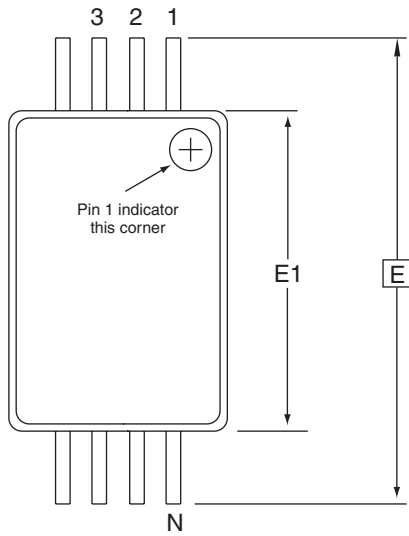
**DRAWING NO.**

8Y1

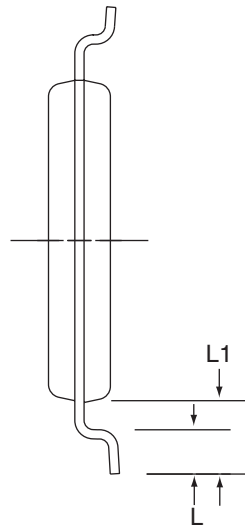
**REV.**

C

8.6 8A2 – TSSOP



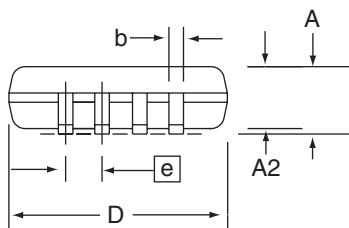
Top View



End View

COMMON DIMENSIONS  
(Unit of Measure = mm)

| SYMBOL | MIN      | NOM  | MAX  | NOTE |
|--------|----------|------|------|------|
| D      | 2.90     | 3.00 | 3.10 | 2, 5 |
| E      | 6.40 BSC |      |      |      |
| E1     | 4.30     | 4.40 | 4.50 | 3, 5 |
| A      | -        | -    | 1.20 |      |
| A2     | 0.80     | 1.00 | 1.05 |      |
| b      | 0.19     | -    | 0.30 | 4    |
| e      | 0.65 BSC |      |      |      |
| L      | 0.45     | 0.60 | 0.75 |      |
| L1     | 1.00 REF |      |      |      |



Side View

- Notes:
1. This drawing is for general information only. Refer to JEDEC Drawing MO-153, Variation AA, for proper dimensions, tolerances, datums, etc.
  2. Dimension D does not include mold Flash, protrusions or gate burrs. Mold Flash, protrusions and gate burrs shall not exceed 0.15 mm (0.006 in) per side.
  3. Dimension E1 does not include inter-lead Flash or protrusions. Inter-lead Flash and protrusions shall not exceed 0.25 mm (0.010 in) per side.
  4. Dimension b does not include Dambar protrusion. Allowable Dambar protrusion shall be 0.08 mm total in excess of the b dimension at maximum material condition. Dambar cannot be located on the lower radius of the foot. Minimum space between protrusion and adjacent lead is 0.07 mm.
  5. Dimension D and E1 to be determined at Datum Plane H.

5/30/02



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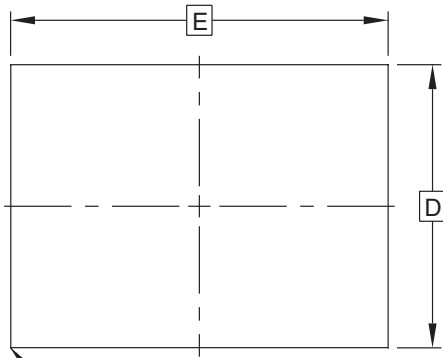
**TITLE**  
8A2, 8-lead, 4.4 mm Body, Plastic  
Thin Shrink Small Outline Package (TSSOP)

**DRAWING NO.**  
8A2

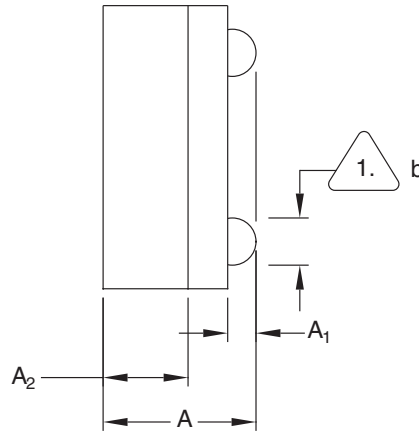
**REV.**  
B



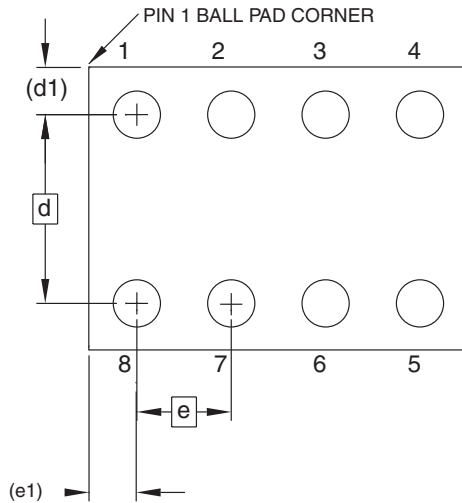
### 8.7 8U3-1 – dBGA2



Top View



Side View



Bottom View  
8 Solder Balls

COMMON DIMENSIONS  
(Unit of Measure = mm)

| SYMBOL | MIN      | NOM  | MAX  | NOTE |
|--------|----------|------|------|------|
| A      | 0.713    | 0.79 | 0.85 |      |
| A1     | 0.09     | 0.14 | 0.19 |      |
| A2     | 0.40     | 0.45 | 0.50 |      |
| b      | 0.20     | 0.25 | 0.30 | 2    |
| D      | 1.50 BSC |      |      |      |
| E      | 2.00 BSC |      |      |      |
| e      | 0.50 BSC |      |      |      |
| e1     | 0.25 REF |      |      |      |
| d      | 1.00 BSC |      |      |      |
| d1     | 0.25 REF |      |      |      |

1. This drawing is for general information only.
2. Dimension 'b' is measured at maximum solder ball diameter

5/3/05



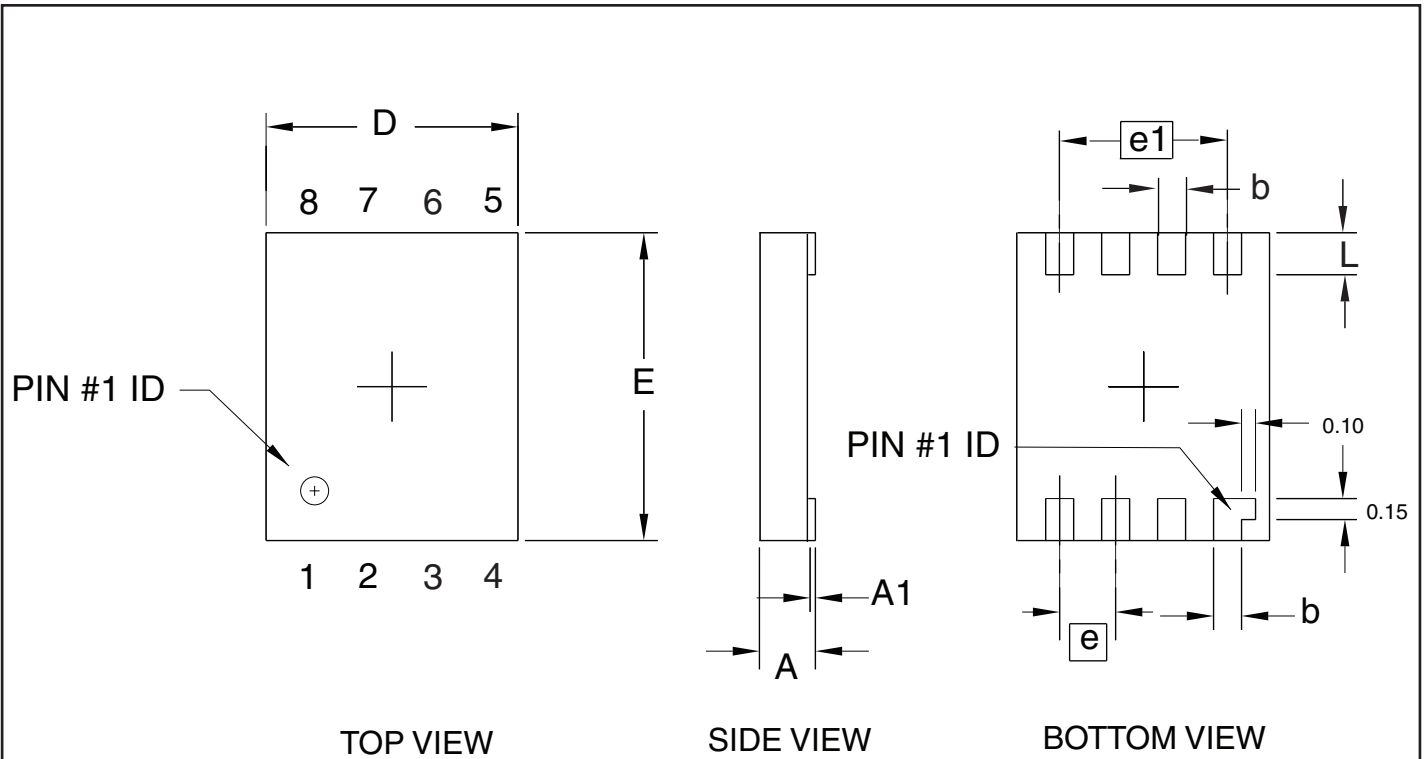
1150E Cheyenne Mt. Blvd  
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TITLE  
8U3-1, 8-ball, 1.50 x 2.00 mm Body, 0.50 mm pitch,  
Small Die Ball Grid Array Package (dBGA2)

DRAWING NO.  
PO8U3-1

REV.  
b

8.8 8D3 - ULA



COMMON DIMENSIONS  
(Unit of Measure = mm)

| SYMBOL | MIN  | NOM      | MAX  | NOTE |
|--------|------|----------|------|------|
| A      | -    | -        | 0.40 |      |
| A1     | 0.00 | -        | 0.05 |      |
| D      | 1.70 | 1.80     | 1.90 |      |
| E      | 2.10 | 2.20     | 2.30 |      |
| b      | 0.15 | 0.20     | 0.25 |      |
| e      |      | 0.40 TYP |      |      |
| e1     |      | 1.20 REF |      |      |
| L      | 0.25 | 0.30     | 0.35 |      |

11/15/05



1150 E. Cheyenne Mtn. Blvd.  
Colorado Springs, CO 80906

TITLE

8D3, 8-lead (1.80 x 2.20 mm Body) Ultra Leadframe  
Land Grid Array (ULLGA) D3

DRAWING NO.

8D3

REV.

0



## 9. Revision History

| Revision No. | Date    | Comments  |
|--------------|---------|---|
| 3378O        | 11/2009 | Added 8S2 package drawing   |
| 3378N        | 1/2009  | Updated 8Y6 package drawing   |
| 3378M        | 7/2008  | Updated Ordering Codes  |
| 3378L        | 11/2007 | Updated to new template<br>Added ULA package offering   |
| 3378K        | 12/2006 | Removed DC/Don't Connect and replaced with NC/No Conenct<br>Adjusted size of Block diagram on pg. 2<br>Made all diagrams on pages 6-9 consistently the same size<br>Corrected 8U3-1 |



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